

FIXED VOLTAGE REGULATOR (POSITIVE)

KK78LXX

3-TERMINAL 0.1A POSITIVE VOLTAGE REGULATORS

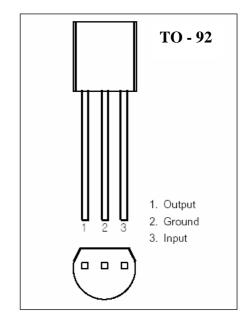
This series of fixed-voltage monolithic integrated-circuit voltage regulators is designed for a wide range of applications.

These applications include on-card regulation for elimination of noise and distribution problems associated with single-point regulation.

In addition, they can be used with power-pass elements to make high current voltage regulators.

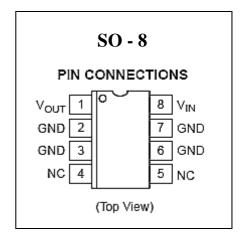
Each of these regulators can deliver up to 100mA output current.

The internal limiting and thermal shutdown features of these regulators make them essentially immune to overload. When used as a replacement for a zener diode-resistor combination, an effective improvement in output impedance can be obtained together with lower-bias current.



FEATURES

- Output current Up to 100mA
- No External Components
- ♦ Internal Thermal Overload Protection
- ♦ Internal Short-Circuit Limiting
- Output Voltage of 5V, 6V, 8V, 9V, 10V, 12V, 15V, 18V and 24V



ABSOLUTE MAXIMUM RATINGS

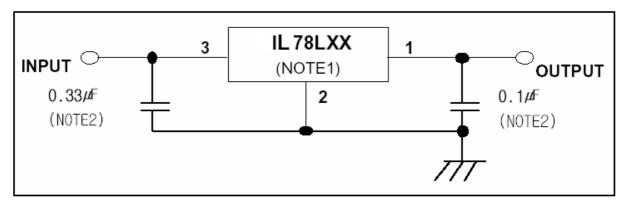
Cha	racteristic	Symbol	Value	Unit
	IL78L05 ~ IL78L10		30	
Input voltage	IL78L12 ~ IL78L18	VI	35	V
	IL78L24		40	
Operating junction temp	erature	Topr	-40 ~ +150	
Storage temperature		Tstg	-65 ~ +150	$^{\circ}\!$
Soldering temperature a	and time	Tsol	260/10sec	



RECOMMENDED OPERATING CONDITIONS

78	Lxx	Min.	Max.	Unit
	IL78L05	7	20	
	IL78L06	8	20	
	IL78L08	10.5	23	
	IL78L09	11.5	24	
Input voltage, VI	IL78L10	12.5	25	V
	IL78L12	14.5	27	
	IL78L15	17.5	30	
	IL78L18	20.5	33	
	IL78L24	26.5	39	
Output current, Io			100	mA
Operating virtual junction ten	nperature, Tj	-40	125	°C

TYPICAL APPLICATION



Notes

- 1. To specify an output voltage, substitute voltage for "XX"
- 2. Bypass capacitors are recommended for optimum stability and transient response and should be located as close as possible to the regulators.



IL78L05 ELECTRICAL CHARACTERISTICS

(At specified virtual junction temperature, VI=10V, Io=40mA (unless otherwise noted)

Characteistic	Symbol	Test cond	ition *	Min	Тур.	Max.	Unit
		25℃		4.8	5	5.2	
Output voltage **	Vout	1mA≤ lo≤ 40mA 7V≤ VI≤ Vmax	-40 ~ 125℃	4.75	5	5.25	V
		1 mA ≤ lo≤ 70 mA		4.75	5	5.25	
Line regulation	Reg line	7≤ VI≤ 20V	- 25℃		32	150	-\/
Line regulation	Neg iiile	8≤ VI≤ 20V	230		26	100	mV
Load regulation	Reg load	1mA≤ lo≤ 100mA	- 25℃		15	60	- mV
Load regulation	rtog lodd	1mA ≤ lo≤ 40mA	230		8	30	
Bias current	I _B		25℃		3.8	6	
Dias current			125℃			5.5	mA
Bias current change	$\triangle I_B$	9≤ VI≤ 20V	-40 ~ 125℃			1.5	Δ.
bias current change	△ıB	1 mA ≤ lo≤ 40 mA	-40 ~ 123 (0.1	- mA
Output noise voltage	V _N	10Hz ≤ f≤ 100kHz	25℃		42		μΝ
Ripple rejection	RR	8≤ VI≤ 20V f=120Hz 25℃		41	49		dB
Dropout voltage	V _D		25℃		1.7		V

Notes

*. Pulse testing techniques are used to maintain the junction temperature as close to the ambient temperature as possible.

Thermal effects must be taken into account separately.

All characteristics are measured with a 0.33μ F capacitor across the input and a 0.1μ F capacitor across the output.



IL78L18 ELECTRICAL CHARACTERISTICS

(At specified virtual junction temperature, VI=23V, Io=40mA (unless otherwise noted)

Characteistic	Symbol	Test cond	ition *	Min	Тур.	Max.	Unit
			25℃	17.3	18	18.7	
Output voltage **	Vout	$1_{\text{mA}} \leq lo \leq 40_{\text{mA}}$ $20.5 \text{V} \leq \text{VI} \leq 33 \text{V}$	-40 ~ 125℃	17.1	18	18.9	V
		1mA≤lo≤ 70mA		17.1	18	18.9	
Line regulation	Reg line	20.5≤ VI≤ 33V	25℃		70	360	V
Line regulation	Keg iirie	22≤ VI≤ 33V	250		64	300	mV
l and an addition	Reg load	1 mA ≤ lo≤ 100 mA	25℃		27	180	mV
Load regulation	ixeg load	1 mA ≤ lo≤ 40 mA	25 C		19	90	
Bias current	1		25℃		4.7	6.5	
Dias current	I _B		125℃			6	mA
Bias current change	^ I	22≤ VI≤ 33V	-40 ~ 125℃			1.5	
bias current change	$\triangle I_{B}$	1 mA ≤ lo≤ 40 mA	-40 ~ 125 C			0.1	- mA
Output noise voltage	V _N	10Hz ≤ f≤ 100kHz	25℃		82		μλ
Ripple rejection	RR	21.5≤ VI≤ 31.5V f=120Hz	25℃	32	36		dB
Dropout voltage	V_D		25℃		1.7		V

Notes

*. Pulse testing techniques are used to maintain the junction temperature as close to the ambient temperature as possible.

Thermal effects must be taken into account separately.

All characteristics are measured with a $0.33\mu F$ capacitor across the input and a $0.1\mu F$ capacitor across the output.



IL78L24 ELECTRICAL CHARACTERISTICS

(At specified virtual junction temperature, VI=26V, Io=40mA (unless otherwise noted)

Characteistic	Symbol	Test cond	ition *	Min	Тур.	Max.	Unit
			25℃	23	24	25	
Output voltage **	Vout	1mA≤ lo≤ 40mA 26.5V≤ VI≤ 39V	-40 ~ 125℃	22.8	24	25.2	V
		1 mA ≤ lo≤ 70 mA		22.8	24	25.2	
Line regulation	26.5≤ VI≤ 39V Reg line 25°C			95	480	V	
Line regulation	Reg IIIle	29≤ VI≤ 39V	25 C		78	400	mV
l and an addition	Reg load	1 mA ≤ lo≤ 100 mA	25℃		41	240	mV
Load regulation	Neg load	1 mA ≤ lo≤ 40 mA	25 C		28	120	
Bias current	I _B		25℃		4.8	6.5	
Dias current			125℃			6	mA
Bias current change	△I _B	28≤ VI≤ 39V	-40 ~ 125℃			1.5	
bias current change	△IB	1 mA ≤ lo≤ 40 mA	-40 ~ 123 (0.1	- mA
Output noise voltage	V _N	10Hz ≤ f≤ 100kHz	25℃		82		μλ
Ripple rejection	RR	27.5≤ VI≤ 37.5V f=120Hz	25℃	30	33		dB
Dropout voltage	V _D		25℃		1.7		V

Notes

*. Pulse testing techniques are used to maintain the junction temperature as close to the ambient temperature as possible.

Thermal effects must be taken into account separately.

All characteristics are measured with a $0.33\mu F$ capacitor across the input and a $0.1\mu F$ capacitor across the output.



IL78L09 ELECTRICAL CHARACTERISTICS

(At specified virtual junction temperature, VI=14V, Io=40mA (unless otherwise noted)

Characteistic	Symbol	Test cond	ition *	Min	Тур.	Max.	Unit
			25℃	806	9	9.4	V
Output voltage **	Vout	1mA≤ lo≤ 40mA 12V≤ VI≤ 24V	-40 ~ 125℃	8.55	9	9.45	
		1 mA ≤ lo≤ 70 mA		8.55	9	9.45	
Line regulation	Reg line	12≤ VI≤ 24V	25℃		45	175	V
Line regulation	Reg line	13≤ VI≤ 24V	25 C		40	125	mV
	Reg load	1mA≤ lo≤ 100mA			19	90	mV
Load regulation	rteg load	1mA ≤ lo≤ 40mA	- 25℃		11	40	IIIV
Bias current	I _B		25℃		4.1	6	
bias current			125℃			5.5	mA
Diag comment shares	<u>. 1</u>	13≤ VI≤ 24V	40, 405%			1.5	
Bias current change	$\triangle I_{B}$	1mA ≤ lo≤ 40mA	-40 ~ 125℃			0.1	- mA
Output noise voltage	V _N	10Hz ≤ f≤ 100kHz	25℃		58		μ
Ripple rejection	RR	13≤ VI≤ 23V f=120Hz	25℃	38	45		dB
Dropout voltage	V_D		25℃		1.7		V

Notes

*. Pulse testing techniques are used to maintain the junction temperature as close to the ambient temperature as possible.

Thermal effects must be taken into account separately.

All characteristics are measured with a $0.33\mu F$ capacitor across the input and a $0.1\mu F$ capacitor across the output.



IL78L10 ELECTRICAL CHARACTERISTICS

(At specified virtual junction temperature, VI=16V, Io=40mA (unless otherwise noted)

Characteistic	Symbol	Test cond	ition *	Min	Тур.	Max.	Unit
			25℃	9.6	10	10.4	
Output voltage **	Vout	1mA≤ lo≤ 40mA 13V≤ VI≤ 25V	-40 ~ 125℃	9.5	10	10.5	V
		1mA≤lo≤ 70mA		9.5	10	10.5	
Line regulation	Reg line	13≤ VI≤ 25V	25℃		51	175	V
Line regulation	Reg iiile	14≤ VI≤ 25V	25 C		42	125	mV
l and an order	Reg load	1mA≤ lo≤ 100mA	25℃		20	90	- mV
Load regulation	Neg load	1 mA ≤ lo≤ 40mA	25 C		11	40	
Bias current	I _B		25℃		4.2	6	
Dias current	'В		125℃			5.5	mA
Bias current change	△I _B	14≤ VI≤ 25V	-40 ~ 125℃			1.5	
bias current change	△IB	1 mA ≤ lo≤ 40mA	-40 ~ 123 (0.1	- mA
Output noise voltage	V _N	10Hz ≤ f≤ 100kHz	25℃		62		μV
Ripple rejection	RR	15≤ VI≤ 25V f=120Hz	25℃	37	44		dB
Dropout voltage	V _D		25℃		1.7		V

Notes

*. Pulse testing techniques are used to maintain the junction temperature as close to the ambient temperature as possible.

Thermal effects must be taken into account separately.

All characteristics are measured with a $0.33\mu F$ capacitor across the input and a $0.1\mu F$ capacitor across the output.



IL78L12 ELECTRICAL CHARACTERISTICS

(At specified virtual junction temperature, VI=17V, Io=40mA (unless otherwise noted)

Characteistic	Symbol	Test cond	ition *	Min	Тур.	Max.	Unit
			25℃ 11		12	12.5	
Output voltage **	Vout	1mA≤ lo≤ 40mA 14V≤ VI≤ 27V	-40 ~ 125℃	11.4	12	12.6	V
		1mA≤lo≤ 70mA		11.4	12	12.6	
Line regulation	Reg line	14.5≤ VI≤ 27V	25℃		55	250	V
Line regulation	Reg line	16≤ VI≤ 27V	25 C		49	200	mV
	Reg load	1mA ≤ lo≤ 100mA			22	100	mV
Load regulation	rteg load	1mA≤ lo≤ 40mA	- 25℃		13	50	IIIV
Bias current	I _B		25℃		4.3	6.5	
bias current			125℃			6	mA
Bias current change	△l _B	16≤ VI≤ 27V	-40 ~ 125℃			1.5	
bias current change	△IB	1 mA ≤ lo≤ 40 mA	-40 ~ 125 C			0.1	- mA
Output noise voltage	V _N	10Hz ≤ f≤ 100kHz	25℃		70		μV
Ripple rejection	RR	15≤ VI≤ 25V f=120Hz	25℃	37	42		dB
Dropout voltage	V_D		25℃		1.7		V

Notes

*. Pulse testing techniques are used to maintain the junction temperature as close to the ambient temperature as possible.

Thermal effects must be taken into account separately.

All characteristics are measured with a $0.33\mu F$ capacitor across the input and a $0.1\mu F$ capacitor across the output.



IL78L15 ELECTRICAL CHARACTERISTICS

(At specified virtual junction temperature, VI=19V, Io=40mA (unless otherwise noted)

Characteistic	Symbol	Test cond	ition *	Min	Тур.	Max.	Unit
			25℃	14.4	15	15.6	
Output voltage **	Vout	1mA≤ lo≤ 40mA 17.5V≤ VI≤ 30V	-40 ~ 125℃	14.25	15	15.75	V
		1 mA ≤ lo ≤ 70 mA		14.25	15	15.75	
Line regulation	Reg line	17.5≤ VI≤ 30V	- 25°C		65	300	V
Line regulation	ixeg iirie	19≤ VI≤ 30V	230		58	250	mV
Load regulation	Reg load	1mA≤ lo≤ 100mA	- 25 ℃		25	150	mV
Load regulation	rteg load	1mA ≤ lo≤ 40mA	230		15	75	
Bias current	I _B		25℃		4.2	6.5	٨
Dias current	'В		125℃			6	mA
Bias current change	△I _B	19≤ VI≤ 30V	-40 ~ 125℃			1.5	Δ.
bias current change	△IB	1 mA ≤ lo≤ 40 mA	-40 ~ 123 (0.1	- mA
Output noise voltage	V _N	10Hz ≤ f≤ 100kHz	25℃		82		μΝ
Ripple rejection	RR	18.5≤ VI≤ 28.5V f=120Hz	25℃	37	44		dB
Dropout voltage	V _D		25℃		1.7		V

Notes

*. Pulse testing techniques are used to maintain the junction temperature as close to the ambient temperature as possible.

Thermal effects must be taken into account separately.

All characteristics are measured with a $0.33\mu F$ capacitor across the input and a $0.1\mu F$ capacitor across the output.



IL78L18 ELECTRICAL CHARACTERISTICS

(At specified virtual junction temperature, VI=23V, Io=40mA (unless otherwise noted)

Characteistic	Symbol	Test cond	ition *	Min	Тур.	Max.	Unit	
			25℃	17.3	18	18.7		
Output voltage **	Vout	$1_{\text{mA}} \leq \text{Io} \leq 40_{\text{mA}}$ $20.5 \text{V} \leq \text{VI} \leq 33 \text{V}$	-40 ~ 125℃	17.1	18	18.9	V	
		1 mA ≤ lo≤ 70 mA		17.1	18	18.9		
Line regulation	Reg line	20.5≤ VI≤ 33V	25℃		70	360		
Line regulation	Reg line	22≤ VI≤ 33V	25 C		64	300	mV	
	Reg load	1mA ≤ lo ≤ 100mA			27	180	ωV	
Load regulation	rteg load	1mA ≤ lo≤ 40mA	25℃		19	90	IIIV	
Bias current	I _B		25℃		4.7	6.5		
bias current			125℃			6	mA	
Diag comment shares	<u> </u>	22≤ VI≤ 33V	40 405 %			1.5		
Bias current change	$\triangle I_{B}$	1mA ≤ lo≤ 40mA	-40 ~ 125℃			0.1	- mA	
Output noise voltage	V _N	10Hz ≤ f≤ 100kHz	25℃		82		μΝ	
Ripple rejection	RR	21.5≤ VI≤ 31.5V f=120Hz	25℃	32	36		dB	
Dropout voltage	V_D		25℃		1.7		V	

Notes

*. Pulse testing techniques are used to maintain the junction temperature as close to the ambient temperature as possible.

Thermal effects must be taken into account separately.

All characteristics are measured with a $0.33\mu F$ capacitor across the input and a $0.1\mu F$ capacitor across the output.



IL78L24 ELECTRICAL CHARACTERISTICS

(At specified virtual junction temperature, VI=26V, Io=40mA (unless otherwise noted)

Characteistic	Symbol	Test cond	ition *	Min	Тур.	Max.	Unit
			25℃	23	24	25	
Output voltage **	Vout	1mA≤ lo≤ 40mA 26.5V≤ VI≤ 39V	-40 ~ 125℃	22.8	24	25.2	V
		1 mA ≤ lo≤ 70 mA		22.8	24	25.2	
Line regulation	26.5≤ VI≤ 39V Reg line 25°C			95	480	V	
Line regulation	Reg IIIle	29≤ VI≤ 39V	25 C		78	400	mV
l and an addition	Reg load	1 mA ≤ lo≤ 100 mA	25℃		41	240	mV
Load regulation	Neg load	1 mA ≤ lo≤ 40 mA	25 C		28	120	
Bias current	I _B		25℃		4.8	6.5	
Dias current			125℃			6	mA
Bias current change	△I _B	28≤ VI≤ 39V	-40 ~ 125℃			1.5	
bias current change	△IB	1 mA ≤ lo≤ 40 mA	-40 ~ 123 (0.1	- mA
Output noise voltage	V _N	10Hz ≤ f≤ 100kHz	25℃		82		μλ
Ripple rejection	RR	27.5≤ VI≤ 37.5V f=120Hz	25℃	30	33		dB
Dropout voltage	V _D		25℃		1.7		V

Notes

*. Pulse testing techniques are used to maintain the junction temperature as close to the ambient temperature as possible.

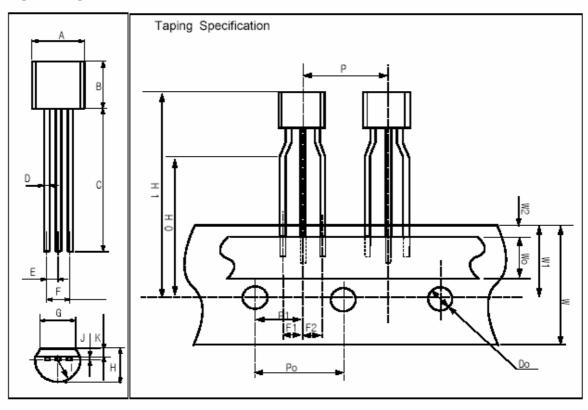
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All characteristics are measured with a $0.33\mu F$ capacitor across the input and a $0.1\mu F$ capacitor across the output.



PACKAGE OUTLINE

[TO-92]



	Package Dime	nsion(unit:mm)		Taping Dimension(unit:mm)				
Symbol	Min	Тур	Max	Symbol	Min	Тур	Max	
Α	4.43	4.58	4.83	Р	12.2	12.7	13.2	
В	4.38	4.58	4.78	PO	12.5	12.7	12.9	
С	14.07	14.47	14.87	P1	5.85	6.35	6.85	
D	0.36	0.46	0.56	F1,F2	2.4	2.5	2.9	
E	1.07	1.27	1.47	w	17.5	18.0	19.0	
F	2.34	2.54	2.74	wo	5.5	6.0	6.5	
G	3.40	3.60	3.80	W1	8.5	9.0	9.5	
н	-	-	3.86	W2	-	-	1.0	
I	-	[R2.29]		но	15.5	16.0	16.5	
J	0.33	0.38	0.39	H1	-	-	27.0	
К	0.92	1.02	1.12	DO	3.8	4.0	4.2	



Mechanical Dimensions (Continued)

Package

8-SOP

